

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V _{DSS}	60	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current (Note 6) V _{GS} = 10V	Steady State	T _A = +25°C	I _D	3.3	A
		T _A = +70°C		2.6	
	t<10s	T _A = +25°C	I _D	4.1	A
		T _A = +70°C		3.4	
Maximum Continuous Body Diode Forward Current (Note 5)			I _S	2.0	A
Pulsed Drain Current (10μs pulse, duty cycle = 1%)			I _{DM}	12	A
Avalanche Current (Note 7) L=0.1mH			I _{AS}	10	A
Avalanche Energy (Note 7) L=0.1mH			E _{AS}	5.9	mJ

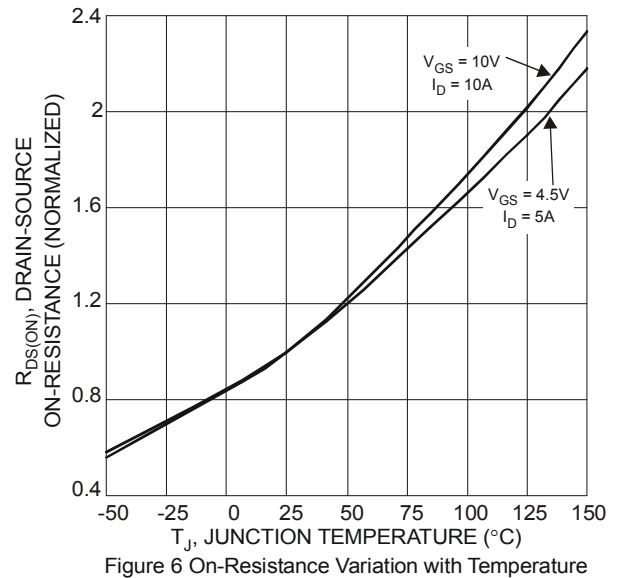
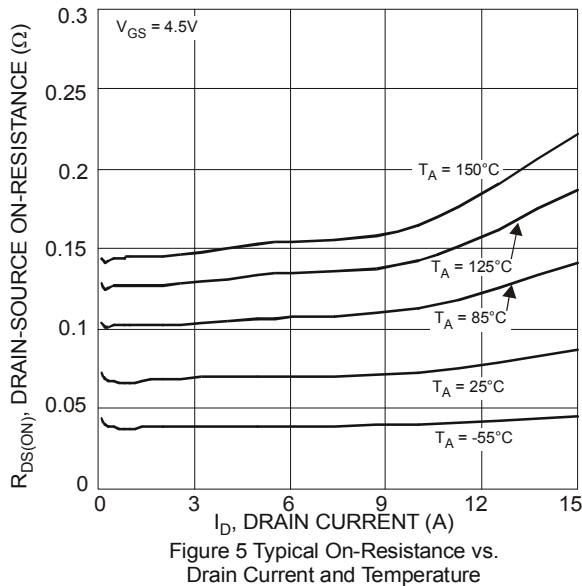
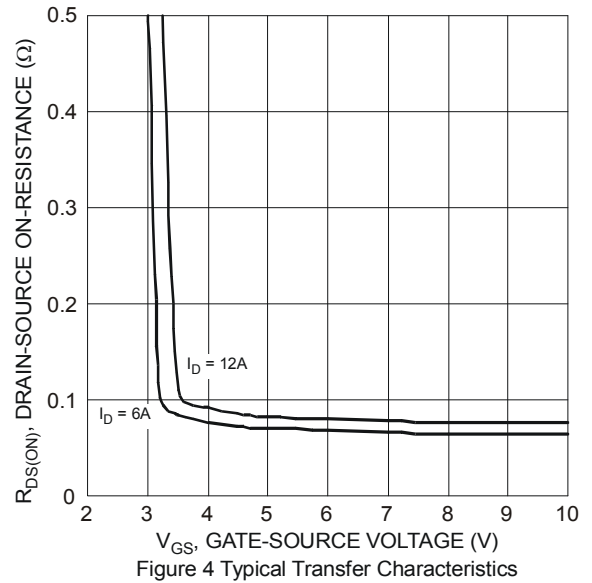
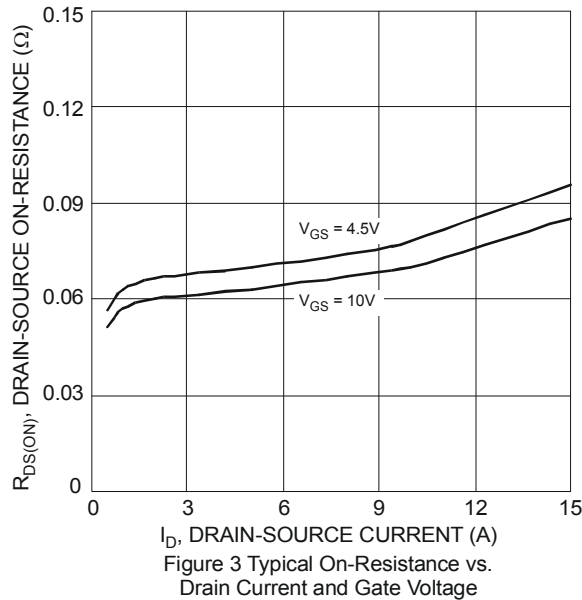
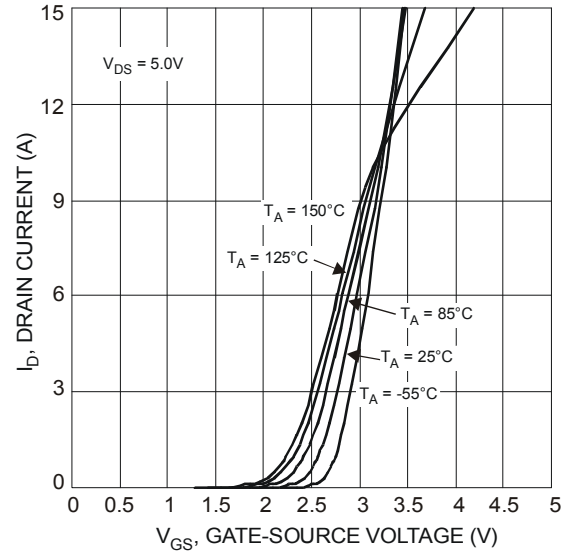
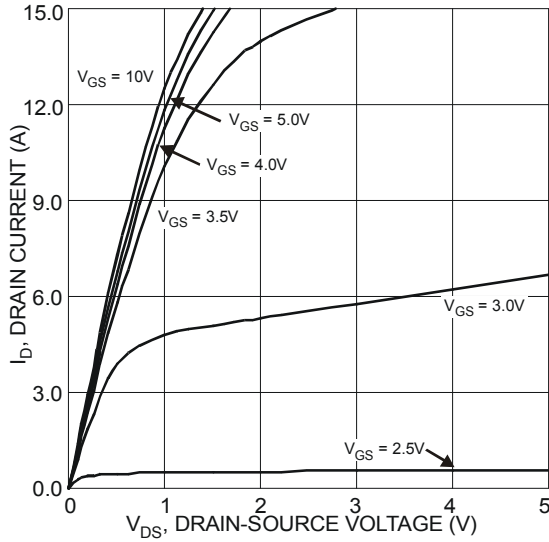
Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

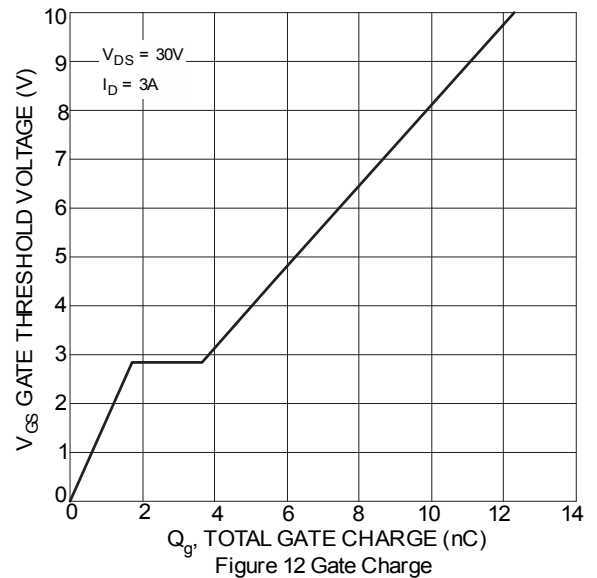
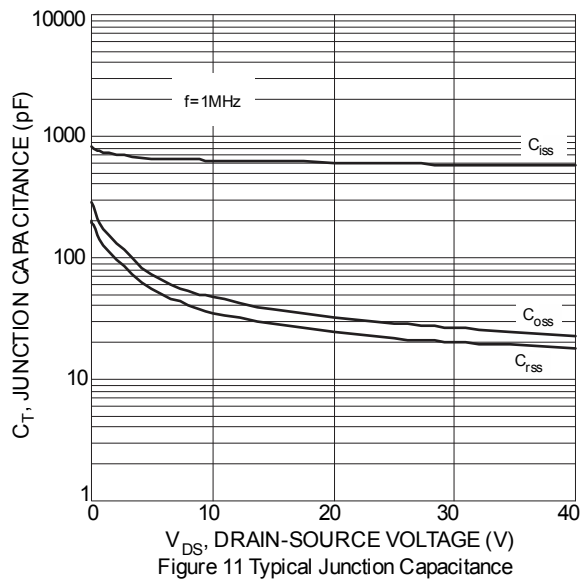
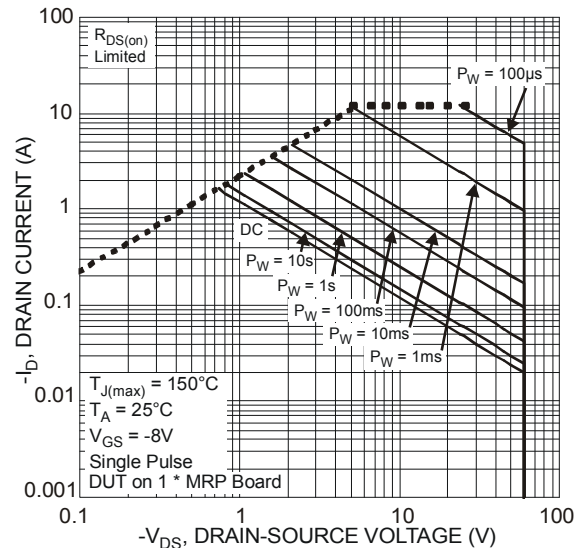
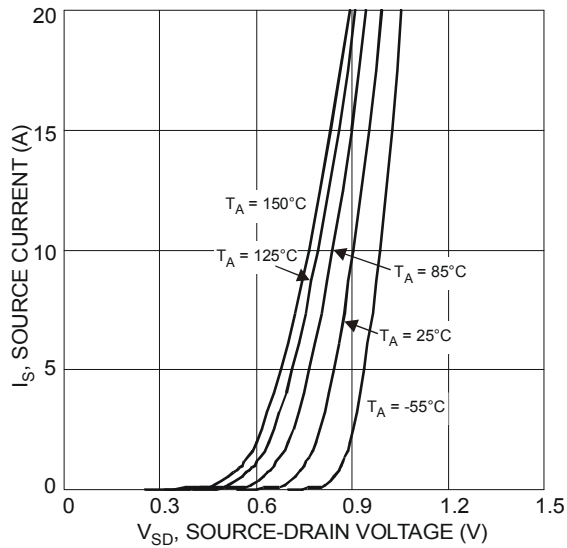
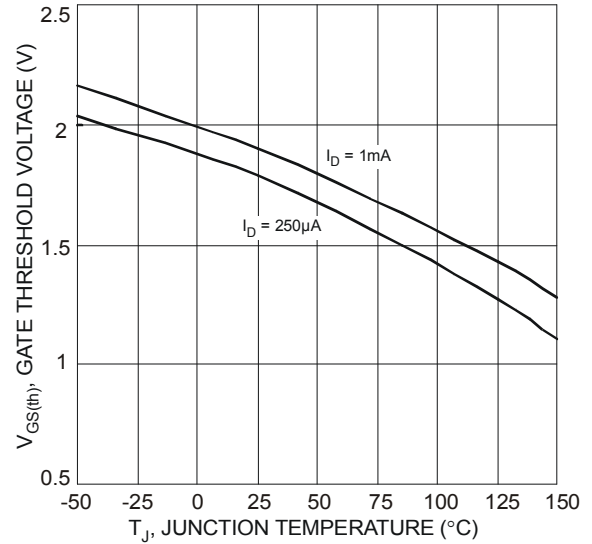
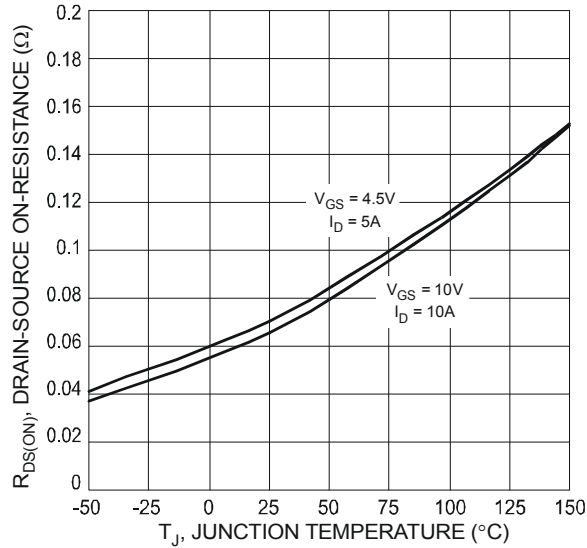
Characteristic			Symbol	Value	Units
Total Power Dissipation (Note 5)			P _D	1.2	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State		R _{θJA}	104	°C/W
	t < 10s			61	
Total Power Dissipation (Note 6)			P _D	1.5	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State		R _{θJA}	83	°C/W
	t < 10s			50	
Thermal Resistance, Junction to Case			R _{θJC}	14.5	
Operating and Storage Temperature Range			T _J , T _{STG}	-55 to +150	°C

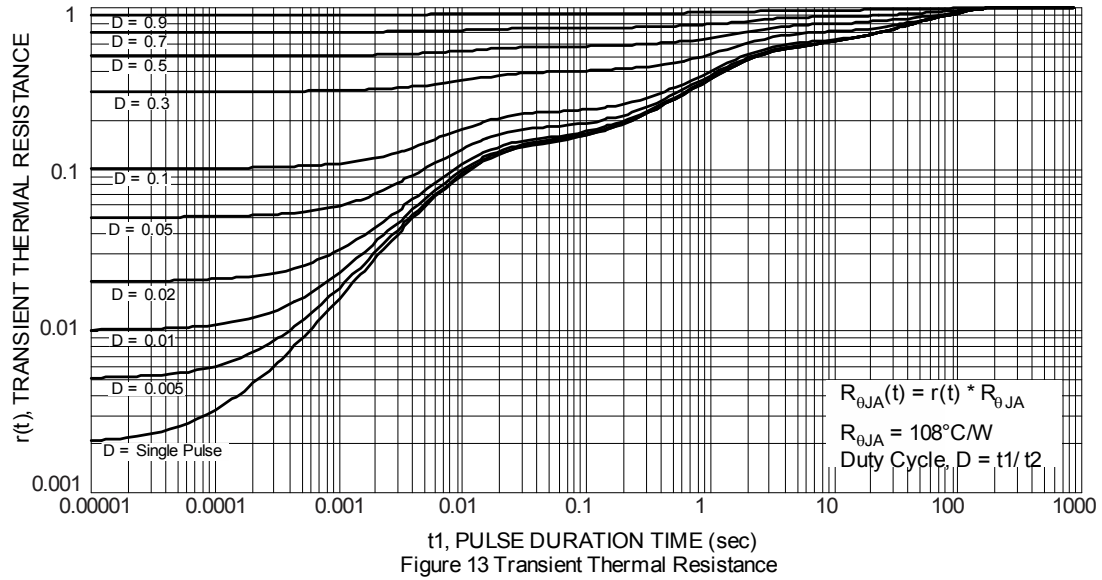
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV _{DSS}	60	—	—	V	I _D = 250µA, V _{GS} = 0V
Zero Gate Voltage Drain Current	I _{DSS}	—	—	1	µA	V _{DS} = 60V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}	—	—	±100	nA	V _{GS} = ±16V, V _{DS} = 0V
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V _{GS(th)}	1.0	—	3.0	V	I _D = 250µA, V _{DS} = V _{GS}
Static Drain-Source On-Resistance	R _{DS(on)}	—	68	80	mΩ	V _{GS} = 10V, I _D = 4.5A
			70	100		V _{GS} = 4.5V, I _D = 3.5A
Diode Forward Voltage	V _{SD}	—	0.75	1.1	V	I _S = 12A, V _{GS} = 0V
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	C _{iss}	—	588	—	pF	V _{DS} = 30V, V _{GS} = 0V f = 1MHz
Output Capacitance	C _{oss}	—	26.5	—		
Reverse Transfer Capacitance	C _{rss}	—	20	—		
Gate Resistance	R _g	—	1.5	—	Ω	V _{GS} = 0V, V _{DS} = 0V, f = 1MHz,
Total Gate Charge (V _{GS} = 4.5V)	Q _g	—	5.6	—	nC	V _{DS} = 30V, I _D = 3A
Total Gate Charge (V _{GS} = 10V)	Q _g	—	12.3	—		
Gate-Source Charge	Q _{gs}	—	1.7	—		
Gate-Drain Charge	Q _{gd}	—	1.9	—		
Turn-On Delay Time	t _{D(on)}	—	3.5	—	nS	V _{DD} = 30V, V _{GS} = 10V R _L ≅ 50Ω, R _G ≅ 20Ω
Turn-On Rise Time	t _r	—	4.1	—		
Turn-Off Delay Time	t _{D(off)}	—	35	—		
Turn-Off Fall Time	t _f	—	11	—		
Body Diode Reverse Recovery Time	t _{rr}	—	18	—	nS	I _S = 12A, dI/dt = 100A/µs
Body Diode Reverse Recovery Charge	Q _{rr}	—	12	—	nC	I _S = 12A, dI/dt = 100A/µs

- Notes:
- Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 - Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 - I_{AS} and E_{AS} rating are based on low frequency and duty cycles to keep T_J = +25°C.
 - Short duration pulse test used to minimize self-heating effect.
 - Guaranteed by design. Not subject to product testing.

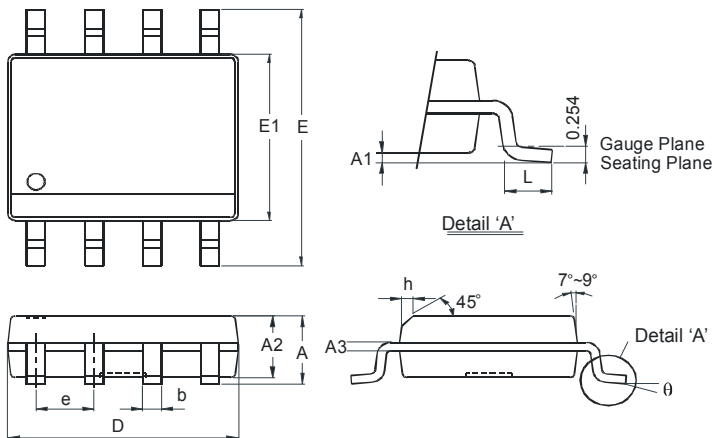






Package Outline Dimensions

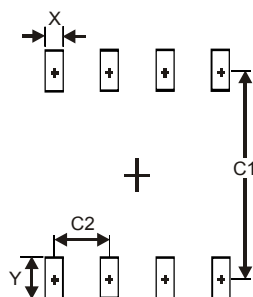
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



SO-8		
Dim	Min	Max
A	-	1.75
A1	0.10	0.20
A2	1.30	1.50
A3	0.15	0.25
b	0.3	0.5
D	4.85	4.95
E	5.90	6.10
E1	3.85	3.95
e	1.27 Typ	
h	-	0.35
L	0.62	0.82
θ	0°	8°
All Dimensions in mm		

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
X	0.60
Y	1.55
C1	5.4
C2	1.27

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